**Product data sheet** 

# 1. General description

Standard reverse recovery power diode in a TO220F package.

### 2. Features and benefits

- · Low forward voltage drop
- Low leakage current
- · High voltage capability
- High inrush current capability

## 3. Applications

- · Input rectifier
- Regulator diode

### 4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Va	lues		Unit
Absolute	maximum rating						
V <sub>RRM</sub> repetitive peak reverse voltage				8	00		V
$I_{F(AV)}$	average forward current	$\delta$ = 0.5 ; square-wave pulse; $T_h \le 100$ °C; Fig. 1; Fig. 2; Fig. 3	10			А	
I <sub>FSM</sub>	non-repetitive peak forward current	$t_p$ = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; Fig. 4				А	
		$t_p$ = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse				Α	
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Static ch	aracteristics						
$V_{F}$	forward voltage	I <sub>F</sub> = 10 A; T <sub>j</sub> = 25 °C; <u>Fig. 6</u>		-	-	1.3	V
		I <sub>F</sub> = 10 A; T <sub>j</sub> = 150 °C; <u>Fig. 6</u>		-	-	1.15	V

# 5. Pinning information

#### **Table 2. Pinning information**

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode	mb	K — A 001aaa020
2	Α	anode		001aaa020
mb	n.c.	mounting base; isolated		

# 6. Ordering information

Table 3. Ordering information

Type number	Package name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date
WND10P08X	TO-220F	WND10P08XQ	Tube	50	TO-220F	14-Apr-2014

## 7. Marking

### Table 4. Marking codes

Type number	Marking codes
WND10P08X	WND10P08X

## 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Values	Unit
$V_{RRM}$	repetitive peak reverse voltage		800	V
$V_{RWM}$	crest working reverse voltage		800	V
$V_R$	reverse voltage	DC	800	V
I <sub>F(AV)</sub>	average forward current	$δ$ = 0.5; square-wave pulse; $T_h \le 100$ °C; Fig. 1; Fig. 2; Fig. 3	10	А
I <sub>FSM</sub>	non-repetitive peak forward current	$t_p$ = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; Fig. 4	180	Α
		$t_p$ = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse	216	Α
T <sub>stg</sub>	storage temperature		-55 to 150	°C
T <sub>j</sub>	junction temperature		150	°C

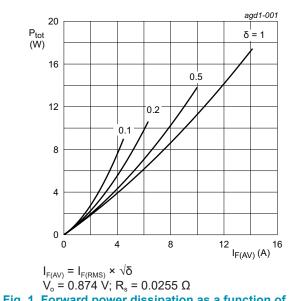
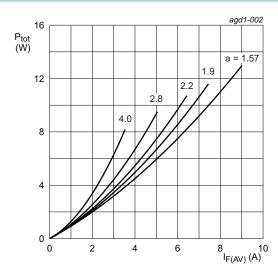


Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values



a = form factor =  $I_{F(RMS)}/I_{F(AV)}$  $V_o$  = 0.874 V;  $R_s$  = 0.0255  $\Omega$ 

Fig. 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values

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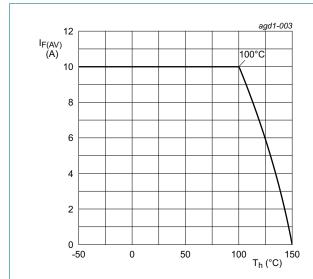


Fig. 3. Forward current as a function of heatsink temperature; maximum values

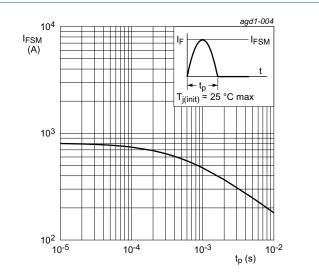


Fig. 4. Non-repetitive peak forward current as a function of pulse width; sinusoidal waveform; maximum values

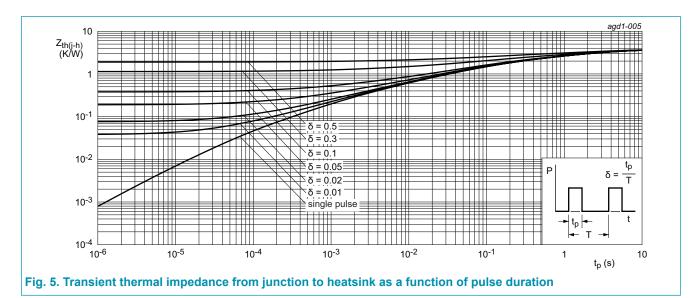
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### 9. Thermal characteristics

### **Table 6. Thermal characteristics**

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-h)}$	thermal resistance from junction to heatsink	<u>Fig. 5</u>	-	-	3.6	K/W
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient free air	in free air	-	55	-	K/W



### 10. Isolation characteristics

#### **Table 7. Isolation characteristics**

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>isol(RMS)</sub>	RMS isolation voltage	50 Hz ≤ f ≤ 60 Hz; RH ≤ 65 %; from all pins to external heatsink; sinusoidal waveform; clean and dust free	-	-	2500	V
C <sub>isol</sub>	isolation capacitance	from cathode to external heatsink	-	10	-	PF

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### 11. Characteristics

### **Table 8. Characteristics**

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	racteristics					
V <sub>F</sub>	forward current	I <sub>F</sub> = 10 A; T <sub>j</sub> = 25 °C; <u>Fig. 6</u>	-	-	1.3	V
		I <sub>F</sub> = 10 A; T <sub>j</sub> = 150 °C; <u>Fig. 6</u>	-	-	1.15	V
I <sub>R</sub>	reverse current	V <sub>R</sub> = 800 V; T <sub>j</sub> = 25 °C	-	-	10	μA
		V <sub>R</sub> = 800 V; T <sub>j</sub> = 150 °C	-	-	1	mA

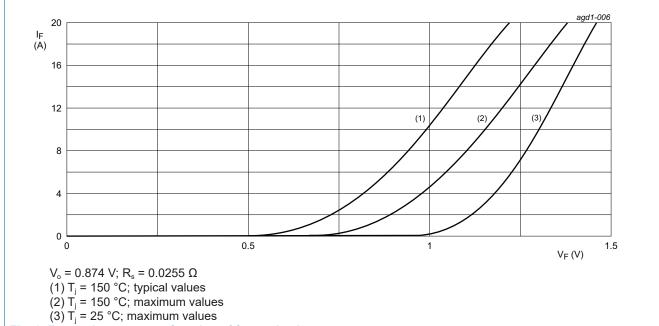
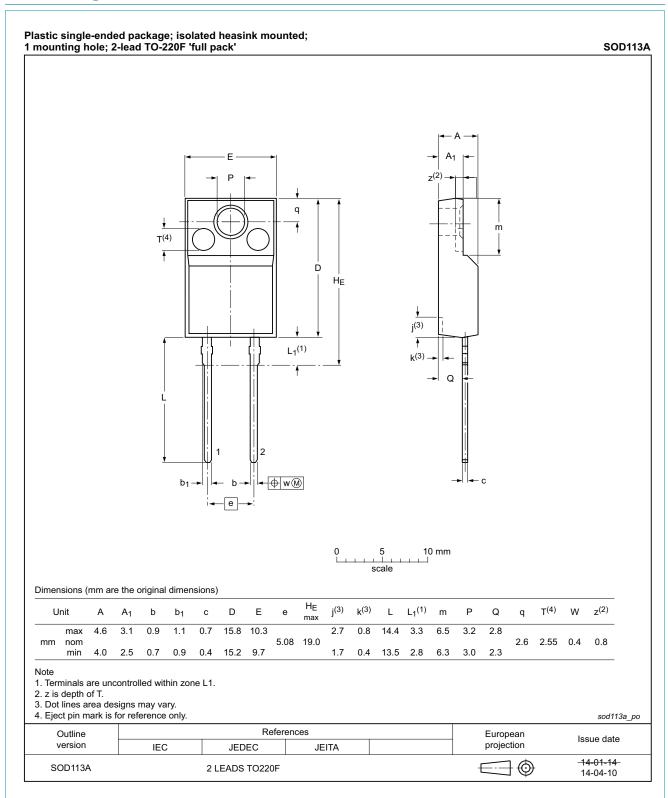


Fig. 6. Forward current as a function of forward voltage

## 12. Package outline



**Product data sheet** 

### 13. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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